- **Compare Two 8-Bit Words**
- **Package Options Include Plastic** Small-Outline (DW) and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

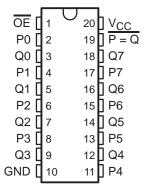
These identity comparators perform comparisons of two 8-bit binary or BCD words. An output-enable (OE) input may be used to force the output to the high level.

The SN54HC688 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74HC688 is characterized for operation from -40°C to 85°C.

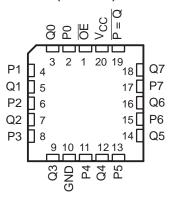
FUNCTION TABLE

INPU [.]	TS	OUTDUT
DATA P, Q	ŌĒ	O <u>UTPU</u> T P = Q
P = Q	L	L
P > Q	X	Н
P < Q	Χ	Н
Х	Н	Н

SN54HC688 . . . J OR W PACKAGE SN74HC688 . . . DW OR N PACKAGE (TOP VIEW)



SN54HC688 . . . FK PACKAGE (TOP VIEW)

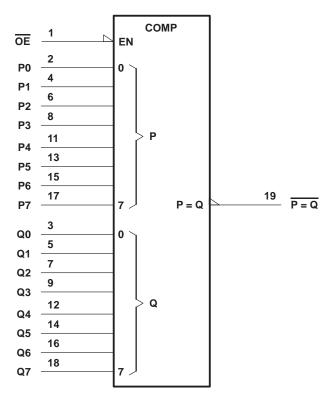




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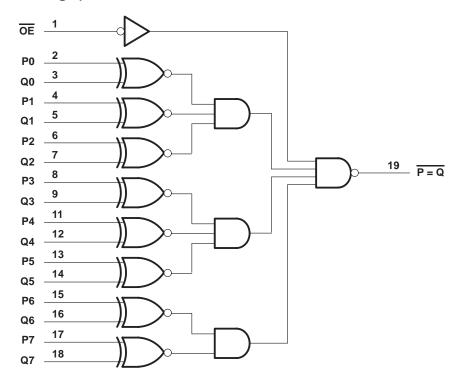


logic symbol†



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





absolute maximum ratings over operating free-air temperature range†

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$) (see No	ote 1) ±20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC}) (see	ee Note 1) ±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC}) \dots$	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Package thermal impedance, θ_{JA} (see Note 2): DW	package 97°C/W
Νp	ackage 67°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

recommended operating conditions

			N2	SN54HC688			SN74HC688		
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage		2	5	6	2	5	6	V
	High-level input voltage	V _{CC} = 2 V	1.5			1.5			V
ViH		V _{CC} = 4.5 V	3.15			3.15			
		V _{CC} = 6 V	4.2			4.2			
		V _{CC} = 2 V	0		0.5	0		0.5	
VIL	Low-level input voltage	V _{CC} = 4.5 V	0		1.35	0		1.35	V
		VCC = 6 V	0		1.8	0		1.8	
VI	Input voltage		0		Vcc	0		VCC	V
Vo	Output voltage		0		VCC	0		VCC	V
		V _{CC} = 2 V	0		1000	0		1000	
t _t	Input transition (rise and fall) time	V _{CC} = 4.5 V	0		500	0		500	ns
		VCC = 6 V	0		400	0		400	
TA	Operating free-air temperature		-55		125	-40		85	°C

^{2.} The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	PARAMETER TEST CONDITIONS		TEST CONDITIONS		V	Т	A = 25°C	;	SN54H	IC688	SN74H	C688	UNIT
PARAMETER	1251 CC	MUITIONS	vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII		
				2 V	1.9	1.998		1.9		1.9			
		I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4				
Voн	VI = VIH or VIL		6 V	5.9	5.999		5.9		5.9		V		
		I _{OH} = -4 mA	4.5 V	3.98	4.3		3.7		3.84				
		$I_{OH} = -5.2 \text{ mA}$	6 V	5.48	5.8		5.2		5.34				
	V_{OL} $V_{I} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 20 μA	2 V		0.002	0.1		0.1		0.1	V		
			4.5 V		0.001	0.1		0.1		0.1			
VOL			6 V		0.001	0.1		0.1		0.1			
		I _{OL} = 4 mA	4.5 V		0.17	0.26		0.4		0.33			
		$I_{OL} = 5.2 \text{ mA}$	6 V		0.15	0.26		0.4		0.33			
lį	$V_I = V_{CC}$ or 0		6 V		±0.1	±100		±1000		±1000	nA		
Icc	$V_I = V_{CC}$ or 0,	I _O = 0	6 V			8		160		80	μΑ		
C _i			2 V to 6 V		3	10		10		10	pF		

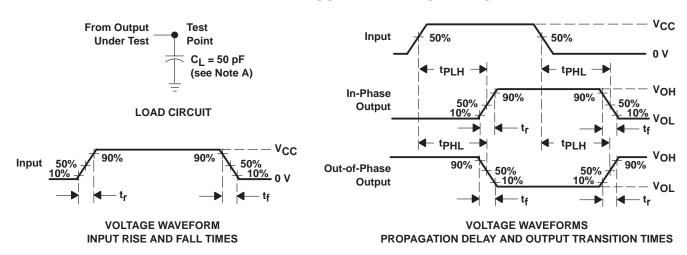
switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	то	T _A = 25°		_Δ = 25°C	;	SN54H	IC688	SN74H	C688	UNIT
PARAMETER		(OUTPUT)	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V		113	210		313		265	
	P or Q	P = Q	4.5 V		30	42		63		53	
.			6 V		24	36		53		45	20
^t pd		P = Q	2 V		66	120		179		151	ns
	ŌĒ		P = Q	4.5 V		16	24		36		30
			6 V		14	20		30		26	
t _t			2 V		38	75		110		95	
		Any	Any	4.5 V		8	15		22		19
			6 V		6	13		19		16	

operating characteristics, T_A = 25°C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load	40	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and test-fixture capacitance.

- B. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \ \Omega$, $t_f = 6 \ ns$, $t_f = 6 \ ns$.
- C. The outputs are measured one at a time with one input transition per measurement.
- D. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

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